

March 2015

FAN48623 — 2500 mA, Synchronous TinyBoost® Regulator with Bypass Mode

Features

- Maximum Continuous Load Current: 2500 mA at V_{IN} of 2.5 V Boosting V_{OUT} to 3.3 V
- Maximum Pulse Load Current of 3.5 A for GSM PAs (1 Slot) and PMIC support simultaneously, V_{IN}=3.1 V, V_{OUT}=3.4 V
- Up to 97% Efficient
- 4 External Components: 2520 case 0.47 µH Inductor and 0603 Case Size Input and Output Capacitors
- Input Voltage Range: 2.5 V to 5.5 V
- Fixed Output Voltage Options: 3.0 V to 5.0 V
- True Bypass Operation when V_{IN} > Target V_{OUT}
- Integrated Synchronous Rectifier
- True Load Disconnect
- Forced Bypass Mode
- V_{SEL} Control to Optimize Target V_{OUT}
- Short-Circuit Protection (SCP)
- Low Operating Quiescent Current
- 16-Bump, 1.81 mm x 1.81 mm, 0.4 mm Pitch, WLCSP

Applications

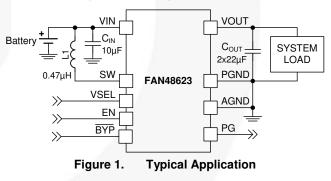
- Boost for Low-Voltage Li-ion Batteries, Brownout Prevention, System PMIC LDOs Supplies, and 2G/3G/4G RF PA Supplies
- Smart Phones, Tablets, Portable Devices

Description

The FAN48623 allows systems to take advantage of new battery chemistries that can supply significant energy when the battery voltage is lower than the required voltage for system power ICs. By combining built-in power transistors, synchronous rectification, and low supply current, this IC provides a compact solution for systems using advanced Lilon battery chemistries.

The FAN48623 is a boost regulator designed to provide a minimum output voltage from a single-cell Li-Ion battery, even when the battery voltage is below system minimum. The output voltage regulation is guaranteed up to a maximum load current of 2500 mA. The regulator transitions smoothly between Bypass and normal Boost Mode. The device can be forced into Bypass Mode to reduce quiescent current.

The FAN48623 is available in a 16-bump, 0.4 mm pitch, Wafer-Level Chip-Scale Package (WLCSP).



Ordering Information

e	er annig mennen						
Part Number	Output Voltage ⁽¹⁾ V _{SEL0} / V _{SEL1}	Operating Temperature	Package	Packing	Device Marking		
FAN48623UC315X	3.15 / 3.330				JK		
FAN48623UC32JX	3.2 / 3.413				JD		
FAN48623UC33X	3.3 / 3.489	-40°C to 85°C	16-Ball, 4x4 Array, 0.4 mm Pitch, 250 μm Ball,	Tape &	JE		
FAN48623UC35X	3.5 / 3.7	-40°C 10 65°C	Wafer-Level Chip-Scale Package (WLCSP) Reel	Reel	JF		
FAN48623UC50X	5.0 / 5.286				JL		
FAN48623UC50GX	5.0 / 5.190				JM		

Note:

1. Other output voltages are available on request. Please contact a Fairchild Semiconductor representative.

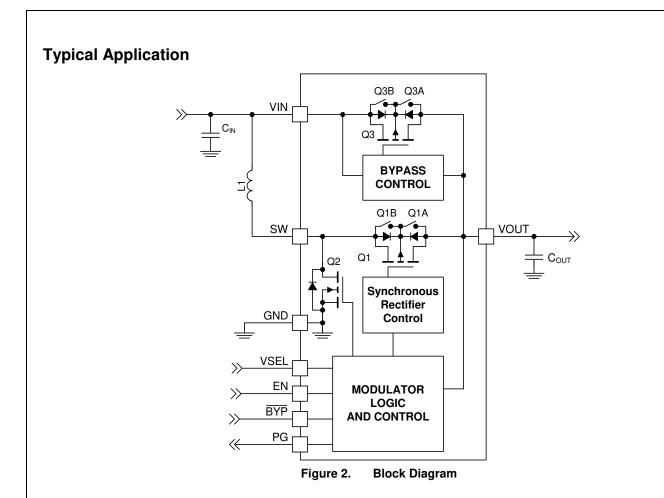


Table 1. Recommended Components

Component	Description	Vendor	Parameter	Тур.	Unit
1.1		Toko: DFE252010P-R47M	L	0.47	μH
L1	0.47 μH, 20%, 5.3 A, 2520	10k0. DFE252010F-R47M	DCR (Series R)	27	mΩ
CIN	10 µF, 20%, 10 V, X5R, 0603	TDK: C1608X5R1A106M	С	10	μF
COUT	$2 \times 22 \mu\text{F}, 20\%, 10 \text{ V}, X5\text{R}, 0603$	TDK: C1608X5R1A226M080AC	С	44	μF

Pin Configuration PG VIN ΕN (A3) (A2)(A4)(A1) (A2) A1 (A3) (A4) VSEL NC VOUT (B3) (B2) (B1) (B4) (B1) B2 (B3) (B4) SW NC BYP (C2) (C1)(C3) (C4) (C2) (C1 (C3) (C4) ••••• · AGND PGND (D1) D4 (D3 (D2 (D2) (D1) (D3) (D4) Figure 4. Bottom View (Bumps Up)

Figure 3. Top-Through View (Bumps Down)

Pin Definitions

Pin #	Name	Description
A1	EN	Enable. When this pin is HIGH, the circuit is enabled.
A2	PG	Power Good . This is an open-drain output. PG is actively pulled LOW if output falls out of regulation due to overload or if thermal protection threshold is exceeded.
A3, A4	VIN	Input Voltage. Connect to Li-Ion battery input power source.
B1	VSEL	Output Voltage Select. When boost is running, this pin can be used to select the output voltage.
B3, B4	VOUT	Output Voltage. Place C _{OUT} as close as possible to the device.
C1	BYP	Bypass . This pin can be used to activate Forced Bypass Mode. When this pin is LOW, the bypass switches (Q3 and Q1) are turned on and the IC is otherwise inactive.
C3, C4	SW	Switching Node. Connect to inductor.
D1	AGND	Analog Ground . This is the signal ground reference for the IC. All voltage levels are measured with respect to this pin. AGND should be connected to PGND at a single point.
D2 — D4	PGND	Power Ground . This is the power return for the IC. The C_{OUT} bypass capacitor should be returned with the shortest path possible to these pins.
B2, C2	NC	No Internal Connection. Note: Bumps are present and should be tied to PGND.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter	Min.	Max.	Unit
V _{IN}	V _{IN} Input Voltage	N Input Voltage		6.5	V
V _{OUT}	V _{OUT} Output Voltage			6.0	V
V	SW/ Nada Valtaga	DC	-0.3	6.0	v
Vsw	SW Node Voltage	Transient: 10 ns, 3 MHz	-1.0	8.0	v
	Other Pins		-0.3	6.5 ⁽²⁾	V
ESD	Electrostatic Discharge	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	2	.0	kV
E9D	Protection Level	Charged Device Model per JESD22-C101	1	.5	ĸv
TJ	Junction Temperature		-40	+150	°C
T _{STG}	Storage Temperature		-65	+150	°C
TL	Lead Soldering Tempera	ature, 10 Seconds		+260	°C

Note:

2. Lesser of 6.5 V or V_{IN} + 0.3 V.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	2.5	4.5	V
I _{OUT}	Output Current	0	2500	mA
T _A	Ambient Temperature	-40	+85	°C
TJ	Junction Temperature	-40	+125	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer Fairchild evaluation boards (1 oz copper on all layers). Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperate T_A .

Symbol	Parameter	Typical	Unit
θ _{JA}	Junction-to-Ambient Thermal Resistance	60	°C/W

Electrical Specifications

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _Q V _{IN} C		Automatic Bypass Mode, V_{OUT_TARGET} =3.3 V, V_{IN} =3.6 V		140	190	μA
	VIN Quiescent Current	Boost Mode, V _{OUT} =3.3 V, V _{IN} =3.0 V		135	180	μA
		Shutdown, EN=0 V, V _{IN} =3.0 V		4.0	12.0	μA
Luc Vour to Ver Rev		Forced Bypass Mode, V _{IN} =3.6 V		6.0	12.0	μA
I _{LK}	V _{OUT} to V _{IN} Reverse Leakage	V _{OUT} =5.0 V, EN=0 V, V _{IN} =0 V		0.5	1.0	μA
I _{LK_OUT}	VIN to VOUT Leakage Current	V _{OUT} =0 V, EN=0 V, V _{IN} =4.2 V		0.1	1.5	μA
V_{UVLO}	Under-Voltage Lockout	V _{IN} Rising		2.20	2.35	V
$V_{\text{UVLO}_{\text{HYS}}}$	Under-Voltage Lockout Hysteresis			200		mV
VIH	Logic Level High EN, VSEL, BYP		1.05			V
VIL	Logic Level Low EN, VSEL, BYP				0.4	V
R _{LOW}	Logic Control Pin Pull Downs (LOW Active)	BYP, VSEL, EN		300		kΩ
I _{PD}	Weak Current Source Pull-Down	BYP, VSEL, EN		100		nA
N/	Output Valtage Assurage	2.5 V \leq V _{IN} \leq V _{OUT_TARGET} -100 mV, DC, 0 to 2500 mA	-1.0		4.0	%
V_{REG}	Output Voltage Accuracy	$2.5 V \le V_{IN} \le V_{OUT_TARGET}$ -100 mV, DC, PWM (CCM) Operation	-1.0		2.5	%
I_{V_LIM}	Boost Valley Current Limit	V _{IN} =2.5 V, V _{OUT} =3.3 V	4.7	5.3		Α
$I_{V_LIM_SS}$	Boost Valley Current Limit During Soft Start	V _{IN} =2.5 V, V _{OUT} =3.3 V		2.6		А
t _{SS}	Soft-Start EN HIGH to Regulation	50 Ω Load, V _{OUT_TARGET} = 3.3 V (Time from EN Rising Edge to 90% of V _{OUT_TARGET})		300		μs
t _{RST}	FAULT Restart Timer			20		ms

Unless otherwise noted and per Figure 1 minimum and maximum values are from V_{IN} =2.5 V to 4.5 V and T_A =-40°C to +85°C. Typical values are at V_{IN} = 3.0 V and T_A = 25°C for all output voltage options.

Note:

3. Minimum and Maximum limits are verified by design, test, or statistical analysis. Typical (Typ.) numbers are not verified, but represent typical results.

Typical Characteristics



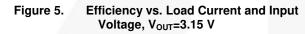
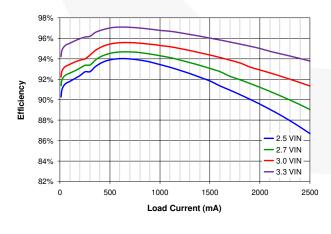
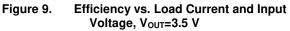




Figure 7. Efficiency vs. Load Current and Input Voltage, V_{OUT}=3.3 V





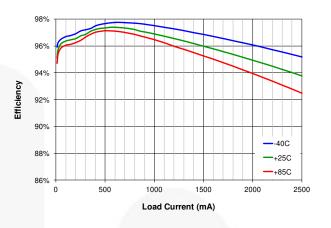


Figure 6. Efficiency vs. Load Current and Temperature, V_{IN} =3.0 V, V_{OUT} =3.15 V

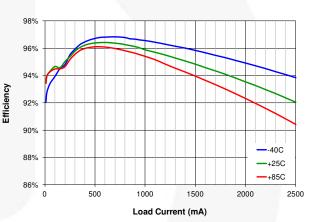
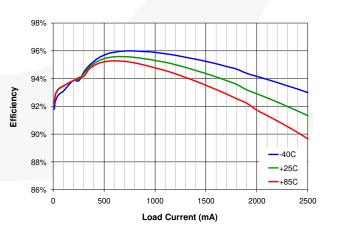
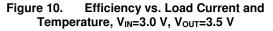


Figure 8. Efficiency vs. Load Current and Temperature, V_{IN}=3.0 V, V_{OUT}=3.3 V





Typical Characteristics (Continued)

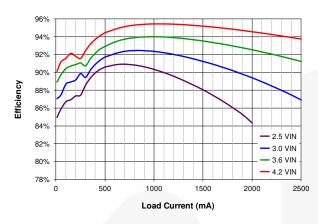
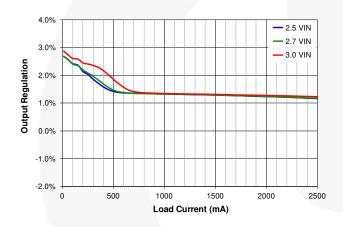
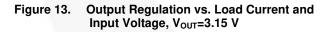
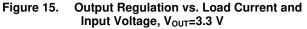


Figure 11. Efficiency vs. Load Current and Input Voltage, V_{OUT}=5.0 V









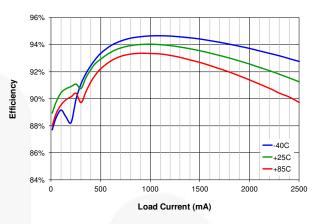


Figure 12. Efficiency vs. Load Current and Temperature, VIN=3.6 V, VOUT=5.0 V

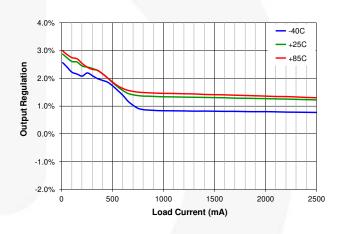
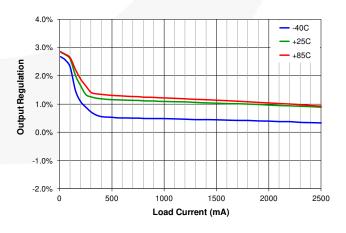
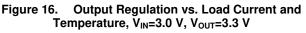


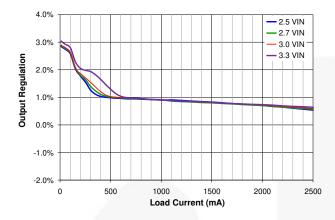
Figure 14. Output Regulation vs. Load Current and Temperature, V_{IN}=3.0 V, V_{OUT}=3.15 V

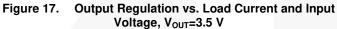


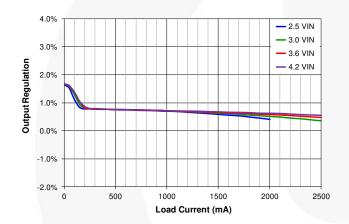


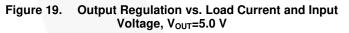
FAN48623 — 2500 mA Synchronous TinyBoostTM Regulator with Bypass Mode

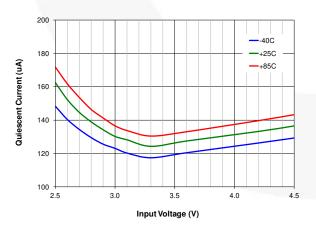
Typical Characteristics (Continued)

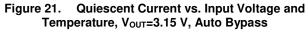












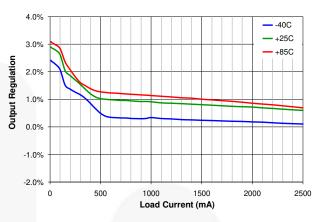


Figure 18. Output Regulation vs. Load Current and Temperature, VIN=3.0 V, VOUT=3.5 V

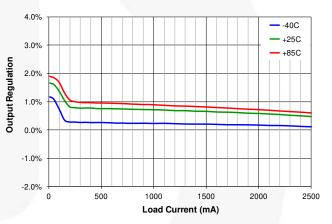
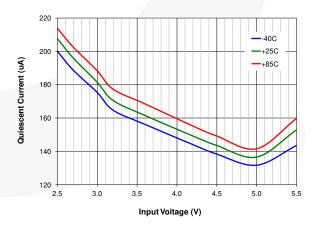
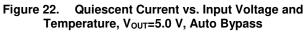


Figure 20. Output Regulation vs. Load Current and Temperature, V_{IN}=3.6 V, V_{OUT}=5.0 V





Typical Characteristics (Continued)

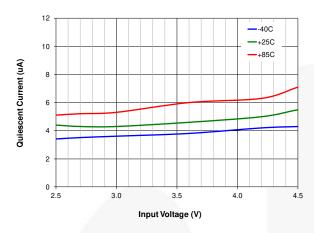


Figure 23. Quiescent Current vs. Input Voltage and Temperature, V_{OUT} =3.3 V, Forced Bypass

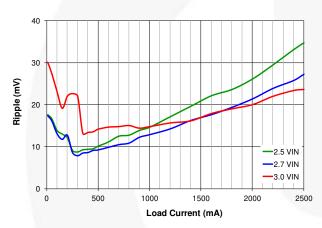
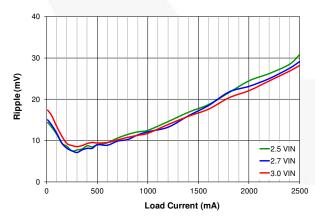
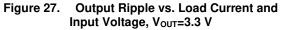


Figure 25. Output Ripple vs. Load Current and Input Voltage, Vout=3.15 V





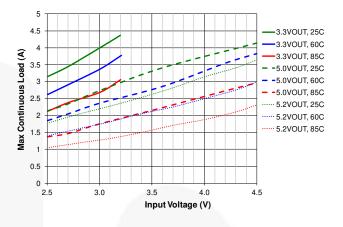


Figure 24. Typical Maximum Continuous Load vs. Input Voltage, Temperature and Output Voltage

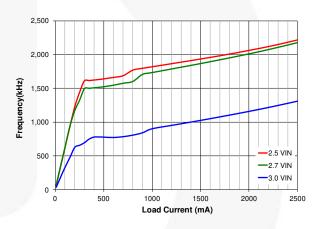
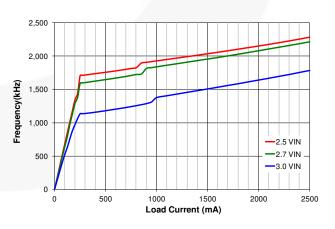
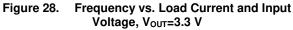


Figure 26. Frequency vs. Load Current and Input Voltage, V_{OUT}=3.15 V





Typical Characteristics (Continued)

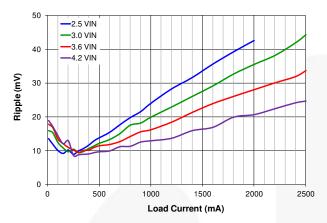


Figure 29. Output Ripple vs. Load Current and Input Voltage, V_{OUT}=5.0 V

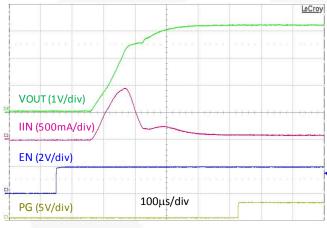


Figure 31. Startup, 50 Ω Load, V_{IN}=2.5 V, V_{OUT}=3.15 V

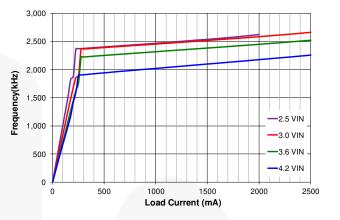


Figure 30. Frequency vs. Load Current and Input Voltage, V_{OUT}=5.0 V

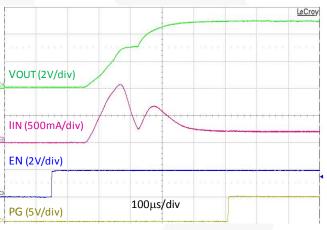


Figure 32. Startup, 50 Ω Load, V_{IN}=3.0 V, V_{OUT}=5.0 V

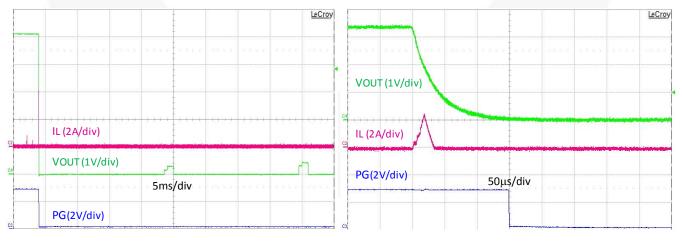
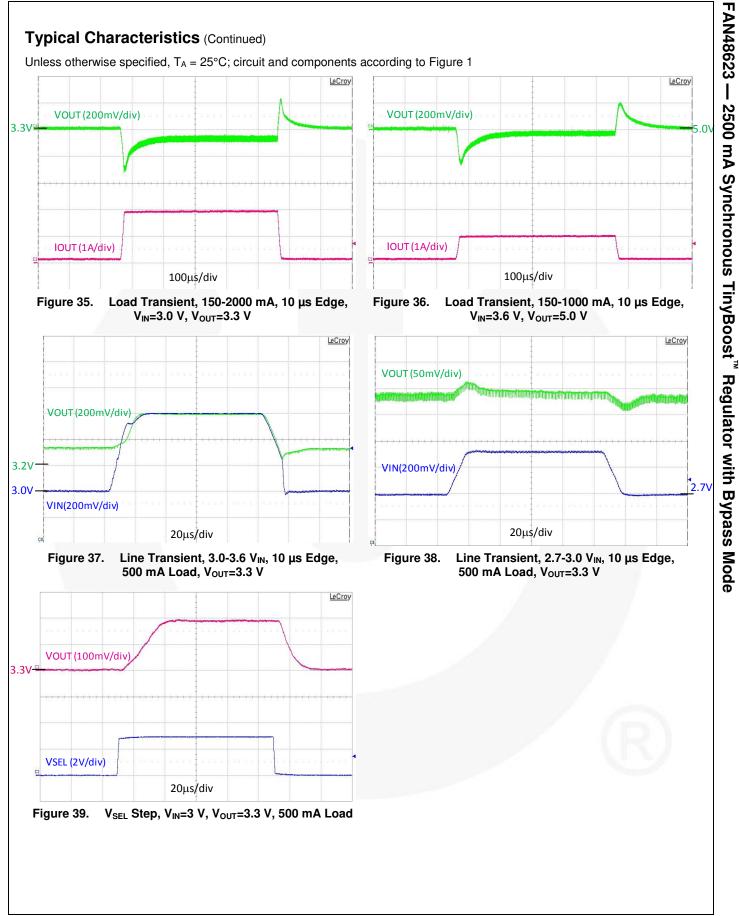


Figure 33. Overload Protection, V_{IN}=3.0 V, V_{OUT}=5.0 V

Figure 34. Output Fault, VIN=3.0 V, VOUT=3.3 V



Circuit Description

FAN48623 is a synchronous boost regulator, typically operating at 2.5 MHz in Continuous Conduction Mode (CCM), which occurs at moderate to heavy load current and low V_{IN} voltages. At light load, the regulator operates at Discontinuous Conduction Mode (DCM) to maintain high efficiency.

FAN48623 uses a current-mode modulator to achieve excellent transient response and smooth transitions between CCM and DCM operation.

The regulator includes a Bypass Mode that automatically activates when V_{IN} is above the boost regulator's set point.

Table 2. Operating States

Mode	Description	Invoked When
LIN	Linear Startup	$V_{IN} > V_{OUT}$
SS	Soft-Start Mode	V _{IN} <v<sub>OUT < Vout_target</v<sub>
BST	Boost Operating Mode	$V_{OUT} = V_{OUT_TARGET}$
BPS	Bypass Mode	$V_{\text{IN}} > V_{\text{OUT}_\text{TARGET}}$

Startup and Shutdown (EN Pin)

If EN is LOW, all bias circuits are off and the regulator is in Shutdown Mode. During shutdown, current flow is prevented from VIN to VOUT, as well as reverse flow from VOUT to VIN. During startup, keep DC current draw below 500 mA until the device successfully executes startup. It is recommended not to connect EN directly to VIN but use a GPIO voltage of 1.8 V to set the logic for the EN pin. The following table describes the startup sequence.

Table 3. Boost Startup Sequence

Start Mode	Entry	Exit	End Mode	Timeout (µs)
	V _{IN} >	$V_{OUT} > V_{IN}$ -300 mV	SS	
LIN1	V _{UVLO} , EN=1	TIMEOUT	LIN2	512
LIN2	LIN1 Exit	$V_{OUT} > V_{IN}$ -300 mV	SS	
LINZ		TIMEOUT	FAULT	1024
SS	LIN1 or LIN2 Exit	V _{OUT} =V _{OUT_TARGET}	BST	

Linear Startup (LIN)

When EN is HIGH and $V_{\text{IN}} > V_{\text{UVLO}}$, the regulator attempts to bring V_{OUT} within 300 mV of V_{IN} using the internal fixed current source from V_{IN} (Q3). The current is limited to the LIN1 (~1 A) set point.

If V_{OUT} reaches $V_{IN}\text{-}300~mV$ during LIN1 Mode, SS Mode is initiated. Otherwise, LIN1 times out after 512 μs and LIN2 Mode is entered.

In LIN2 Mode, the current source is incremented to approximately 2 A. If V_{OUT} fails to reach V_{IN} -300 mV after 1024 μ s, a fault state is declared.

Soft-Start Mode (SS)

Upon successful completion of the LIN Mode ($V_{OUT\geq}V_{IN}$ -300 mV), SS Mode begins and the regulator starts switching with boost valley current limited to 50% of nominal level at Boost Mode.

During SS Mode, V_{OUT} is ramped up by stepping the internal reference. If V_{OUT} fails to reach the voltage required during the SS ramp sequence within 64 μ s, a fault state is declared.

Boost Mode (BST)

This is a normal operating state of the regulator.

Bypass Mode (BPS)

If V_{IN} is above $V_{\text{OUT_TARGET}}$ when the SS Mode successfully completes, the device transitions directly to BPS Mode.

FAULT State

The regulator enters the FAULT state under any of the following conditions:

- V_{OUT} fails to achieve the voltage required to advance from LIN state to SS state.
- V_{OUT} fails to achieve the voltage required to advance from SS state to BST state.
- Boost valley current limit triggers for 2 ms during the BST state.
- V_{IN} to V_{OUT} voltage drop exceeds 160 mV during BPS state.
- V_{IN} < V_{UVLO}

If a fault is triggered, the regulator stops switching and presents a high-impedance path between VIN and VOUT. After waiting 20 ms, an automatic restart is attempted.

Power Good

Power good is defined as a 0-FAULT, 1-POWER GOOD, open-drain output. The Power Good pin (PG) signals when the regulator has successfully completed soft-start with no faults occurring. Power Good also functions as a warning flag for high die temperature.

- PG is released HIGH when the soft-start sequence is successfully completed.
- Any FAULT state causes PG to be de-asserted.
- PG is not asserted during Forced Bypass exit to Boost Mode until the soft-start sequence is successfully completed.

Over-Temperature

When the die temperature exceeds 125°C, PG de-asserts and the output remains regulated. PG is re-asserted when the device cools by approximately 20°C.

The regulator shuts down if the die temperature exceeds 150°C. Restart occurs when the IC has cooled by approximately 20°C.

Automatic Bypass

In normal operation, the device automatically transitions from Boost Mode to Bypass Mode if V_{IN} goes above V_{OUT_TARGET}. In Bypass Mode, the device fully enhances both Q1 and Q3 to provide a very low impedance path from VIN to VOUT. Entry into the Bypass Mode is triggered when V_{IN} > V_{OUT_TARGET} and no switching has occurred during the past 10 µs. To soften the entry into Bypass Mode, Q3 is driven as a linear current source for the first 5 µs. Bypass Mode exit is triggered when V_{OUT} reaches V_{OUT_TARGET}. During Automatic Bypass Mode, the device is short-circuit protected by voltage comparator tracking the voltage drop from V_{IN} to V_{OUT}; if the drop exceeds 160 mV, a fault state is declared.

With sufficient load to enforce CCM operation, the Bypass Mode to Boost Mode transition occurs at the target V_{OUT} . The Bypass Mode exit threshold has a 50 mV hysteresis imposed at V_{OUT} to prevent cycling between modes. The corresponding input voltage at the transition point is:

$$V_{\mathbb{N}} \leq V_{\text{OUT}} + I_{\text{LOAD}} \bullet (\text{DCR}_{\text{L}} + R_{\text{DS(ON)P}}) || R_{\text{DS(ON)BYP}} - 50 \text{mV}$$
(1)

The Bypass Mode entry threshold has a 30 mV hysteresis imposed at V_{OUT} to prevent cycling between modes. The transition from Boost Mode to Bypass Mode occurs at the target V_{OUT} +30 mV. The corresponding input voltage is:

$$V_{\rm IN} \ge V_{\rm OUT} + I_{\rm LOAD} \bullet (DCR_{\rm L} + R_{\rm DS(ON)P}) + 30mV$$
⁽²⁾

Forced Bypass

Forced Bypass Mode is activated by pulling BYP pin LOW. Forced Bypass Mode initiates with a current limit on Q3 and then proceeds to the Bypass Mode with both Q1 and Q3 fully enhanced. To prevent reverse current to the battery, the device waits until output discharges below V_{IN} before entering Forced Bypass Mode.

After the transition is complete, most of the internal circuitry is disabled to minimize quiescent current. OCP, UVLO and OTP are inactive in Forced Bypass Mode.

By pulling $\overline{\text{BYP}}$ pin HIGH, the part transitions from Forced Bypass Mode to Boost Mode. During the transition, Q1 is off and Q3 is driven as a linear current source for the first 5 µs before entering Boost Mode.

Application Information

Output Capacitance (C_{OUT}) Stability

The effective capacitance $(C_{\text{EFF}}^{(4)})$ of small, high-value, ceramic capacitors decrease as bias voltage increases, as illustrated in Figure 40.

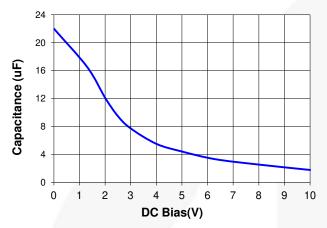


Figure 40. C_{EFF} for 22 μF, 0603, X5R, 10 V-Rated Capacitor (TDK C1608X5R1A226M080AC)

Stable operation is guaranteed with the minimum value of C_{EFF} ($C_{\text{EFF}(\text{MIN})}$), as outlined in Table 4.

Table 4.	Minimum	CEFF	Required	for	Stability
----------	---------	------	----------	-----	-----------

Operating	Operating Conditions				
V _{OUT} (V)	l _{LOAD} (mA)	C _{EFF(MIN)} (μF)			
3.15	0 to 2500	9			
5.0	0 to 2500	6			

Note:

4. C_{EFF} varies with manufacturer, material, and case size.

Inductor Selection

Recommended nominal inductance value is 0.47 µH.

The FAN48623 employs valley-current limiting. Peak inductor current can reach 6.5 A for a short duration during overload conditions. Saturation effects cause the inductor current ripple to become higher under high loading as only the valley of the inductor current ripple is controlled.

Startup Inrush Current Limit

Input current limiting is in effect during soft-start, which limits the current available to charge C_{OUT} and any additional capacitance on the V_{OUT} line. If the output fails to achieve regulation within the set limit, a FAULT occurs, causing the circuit to shut down then restart after 20 ms. If the total combined output capacitance is very high, the circuit may not start on the first attempt, but eventually achieves regulation if no load is present. If a high-current load and high capacitance are both present during soft-start, the circuit may fail to achieve regulation and continually attempts softstart, only to have the output capacitance discharged by the load when in a FAULT state.

Output Voltage Ripple

Output voltage ripple is inversely proportional to C_{OUT} . During t_{ON} , when the boost switch is on, all load current is supplied by C_{OUT} . Output ripple is calculated as:

$$V_{RIPPLE(P-P)} = t_{ON} \bullet \frac{I_{LOAD}}{C_{OUT}}$$
(3)

and

$$t_{ON} = t_{SW} \bullet D = t_{SW} \bullet \left(1 - \frac{V_N}{V_{OUT}}\right)$$
(4)

therefore:

$$V_{RIPPLE(P-P)} = t_{SW} \bullet \left(1 - \frac{V_N}{V_{OUT}}\right) \bullet \frac{I_{LOAD}}{C_{OUT}}$$
(5)

and

1

$$f_{SW} = \frac{1}{f_{SW}}$$
(6)

As can be seen from Equation (5), the maximum V_{RIPPLE} occurs when V_{IN} is at minimum and I_{LOAD} is at maximum.

Voltage at VOUT

For applications where a foreign voltage source could be applied at VOUT, care should be taken to ensure V_{OUT} never exceeds the Absolute Maximum Rating.

Layout Recommendations

The layout recommendations below highlight various layers using different colors.

To minimize spikes at $V_{\text{OUT}},\,C_{\text{OUT}}$ must be placed as close as possible to PGND and VOUT, as shown in Figure 41.

For thermal reasons, it is suggested to maximize the pour area for all planes other than SW. Especially the ground pour should be set to fill all available PCB surface area and tied to internal layers with a cluster of thermal vias.

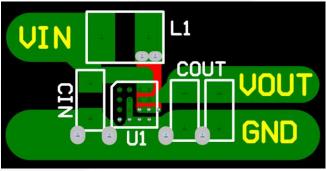
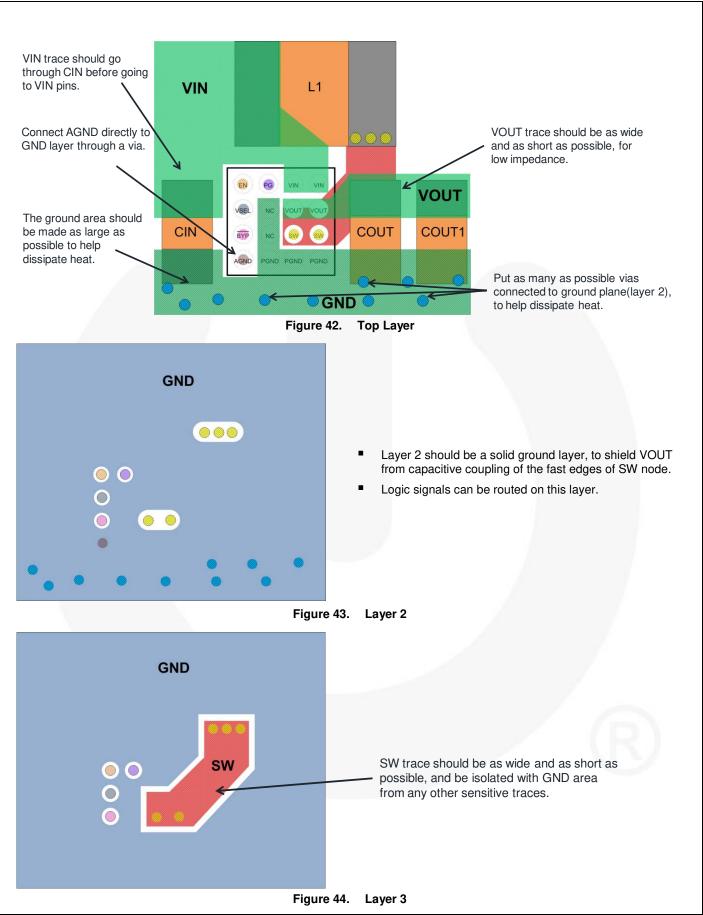


Figure 41. Layout Recommendation

Refer to the section below for detailed layout recommendations for each layer.

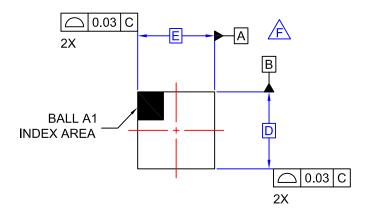


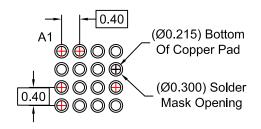
15

FAN48623 — 2500 mA Synchronous TinyBoostTM Regulator with Bypass Mode

Product-Specific Dimensions

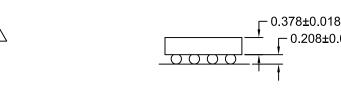
Product	D	E	x	Y
FAN48623UC315X	1.810 ±0.030	1.810 ±0.030	0.305	0.305
FAN48623UC32JX	1.810 ±0.030	1.810 ±0.030	0.305	0.305
FAN48623UC33X	1.810 ±0.030	1.810 ±0.030	0.305	0.305
FAN48623UC35X	1.810 ±0.030	1.810 ±0.030	0.305	0.305
FAN48623UC50X	1.810 ±0.030	1.810 ±0.030	0.305	0.305
FAN48623UC50GX	1.810 ±0.030	1.810 ±0.030	0.305	0.305





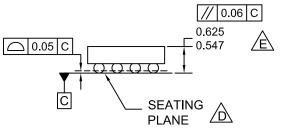
0.208±0.021

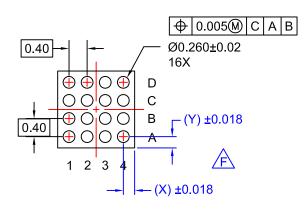
RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



SIDE VIEWS



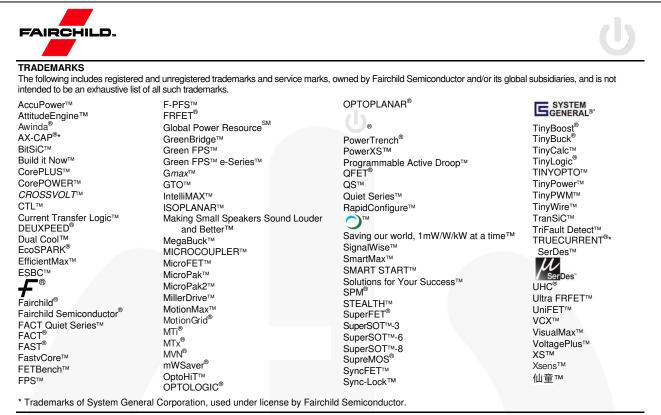




BOTTOM VIEW

NOTES

- A. NO JEDEC REGISTRATION APPLIES.
- **B. DIMENSIONS ARE IN MILLIMETERS.**
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- /D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
 - E. PACKAGE NOMINAL HEIGHT IS
- 586 ± 39 MICRONS (547-625 MICRONS). /F.\FOR DIMENSIONS D,E,X, AND Y SEE
 - PRODUCT DATASHEET.
- G. DRAWING FILNAME: MKT-UC016AF rev1



DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev. 173